

DL6 高磁通耐热冲击材料
HIGH FLUX & THERMAL SHOCK RESISTANT FERRITE

DL6 为镍锌铁氧体材料，初始磁导率 (μ_i) 约 300，饱和磁通密度 (B_s) 约 440 mT (25 °C) / 370 mT (100 °C)，居里温度高于 260 °C。此材料以略低的磁导率换取全系列最高的磁通密度与温度上限——100 °C 仍保有 370 mT， T_c 高于 260 °C，可承受极端温度循环 (−40 °C 至 +200 °C) 与高温回流焊；低磁通下相对损耗因子 20×10^{-6} (0.1 MHz) / 50×10^{-6} (2.0 MHz)，中高频损耗仍低。典型应用为极端温度环境下的高功率电感与射频滤波器，以及航空航天、油井勘探等专用磁性元件，支持车规与军规电源系统的高电流、高磁通设计，亦适合高可靠性 SMD 元件。在 DL 系列中，DL6 是极限工况版：相较 DL5 (B_s 约 420 mT、 $T_c > 240$ °C) 再往磁通与耐温推进一级，代价是标称磁导率略低、达到同样感量需要较多匝数；若温度与磁通需求未达极端等级，DL5 通常是更均衡的选择。

DL6 is a NiZn ferrite with an initial permeability (μ_i) of approx. 300, a saturation flux density (B_s) of approx. 440 mT at 25 °C (370 mT at 100 °C) and a Curie temperature above 260 °C. It trades a slightly lower permeability for the family's highest flux density and temperature ceiling — 370 mT still available at 100 °C and a Curie point above 260 °C — withstanding extreme temperature cycling (−40 °C to +200 °C) and high-temperature reflow; the relative loss factor stays low into the mid/high-frequency range (20×10^{-6} at 0.1 MHz / 50×10^{-6} at 2.0 MHz). Typical uses are high-power inductors and RF filters in extreme-temperature environments, dedicated magnetics for aerospace and downhole exploration, and high-current, high-flux designs in automotive- and military-grade power systems, as well as high-reliability SMD parts. Within the DL family, DL6 is the extreme-duty grade: over DL5 (B_s approx. 420 mT, $T_c > 240$ °C) it pushes flux density and temperature one step further at the cost of a slightly lower nominal permeability — more turns for the same inductance; when conditions are less extreme, DL5 is usually the more balanced choice.

- High-Power Inductor
- RF Filter
- Aerospace / Downhole Magnetics
- Automotive / Military Power

电磁特性 MAGNETIC CHARACTERISTICS

特性 Characteristic	条件 Condition	值 Value	单位 Unit
初始磁导率 μ_i Initial Permeability	100 kHz & <0.2 mT	300±25%	
饱和磁通密度 B_s Saturation Flux Density	3000 A/m · 25 °C 100 Hz	440	mT
饱和磁通密度 B_s Saturation Flux Density	3000 A/m · 100 °C 100 Hz	370	mT
残留磁通密度 B_r Remanence	3000 A/m · 25 °C 100 Hz	300	mT
残留磁通密度 B_r Remanence	3000 A/m · 100 °C 100 Hz	204	mT
矫顽力 H_c Coercivity	3000 A/m · 25 °C 100 Hz	57.7	A/m
矫顽力 H_c Coercivity	3000 A/m · 100 °C 100 Hz	44.3	A/m
$\alpha_{\mu r}$ (温度系数) Temperature coefficient of permeability	20 ~ 60 °C	25	$\times 10^{-6}/K$
相对损耗因子 $\tan\delta/\mu_i$ Relative Loss Factor	0.1 MHz & <0.2 mT	20	$\times 10^{-6}$
相对损耗因子 $\tan\delta/\mu_i$ Relative Loss Factor	2.0 MHz & <0.2 mT	50	$\times 10^{-6}$
居里温度 T_c Curie Temp.	100 kHz & <0.2 mT	>260	°C
密度 D Density	阿基米德法 Archimedes method	5.2	g/cm ³
电阻率 ρ Volume Resistivity	直流电流 DC Current	10 ⁷	$\Omega \cdot m$
功率损耗 P_{cv} Power Loss	32 kHz / 125 mT · 25 °C/100 °C/120 °C	390 / 278 / 254	kW/m ³
功率损耗 P_{cv} Power Loss	64 kHz / 100 mT · 25 °C/100 °C/120 °C	600 / 410 / 375	kW/m ³
功率损耗 P_{cv} Power Loss	100 kHz/100 mT 500 kHz/30 mT 1 MHz/30 mT · 25 °C	1063 451 1112	kW/m ³

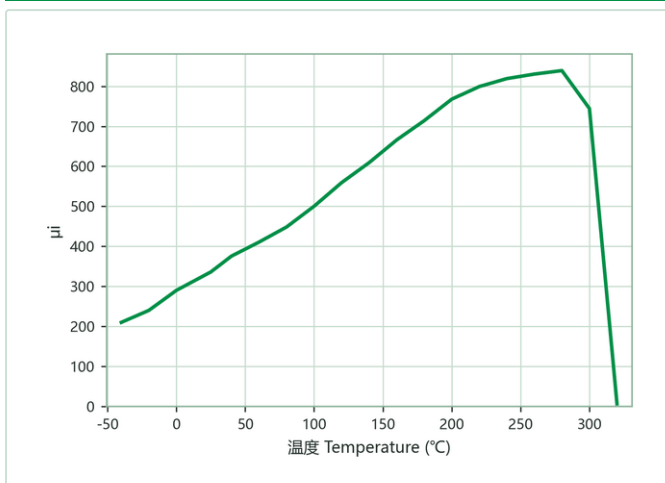
备注：各项数值均为环形磁芯 T31×19×8 测得的典型数值，由于几何形状和尺寸的影响，产品规格将与这些数据有所差异。25 °C 之功率损耗 P_{cv} 为 T31×19×8 环形磁芯绕线 3 匝实测。

Note: all values are typical data measured on a T31×19×8 toroidal core; actual product specifications will vary with geometry and size. P_{cv} values at 25 °C are measured on a T31×19×8 toroid wound with 3 turns.

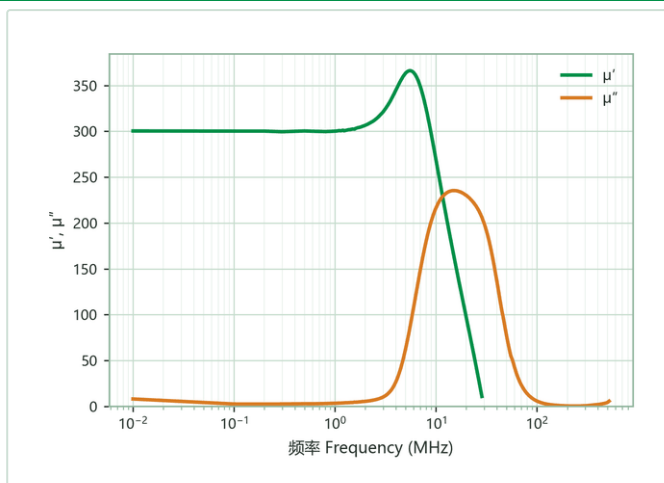
特性曲线详见次页 CHARACTERISTIC CURVES — SEE NEXT PAGE

DL6

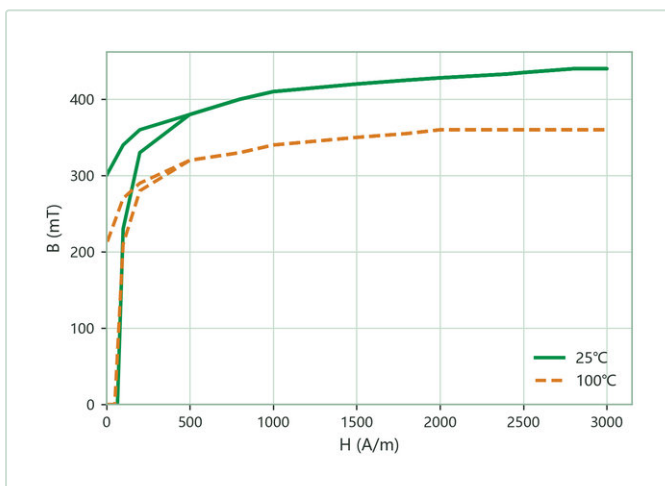
特性曲线 CHARACTERISTIC CURVES



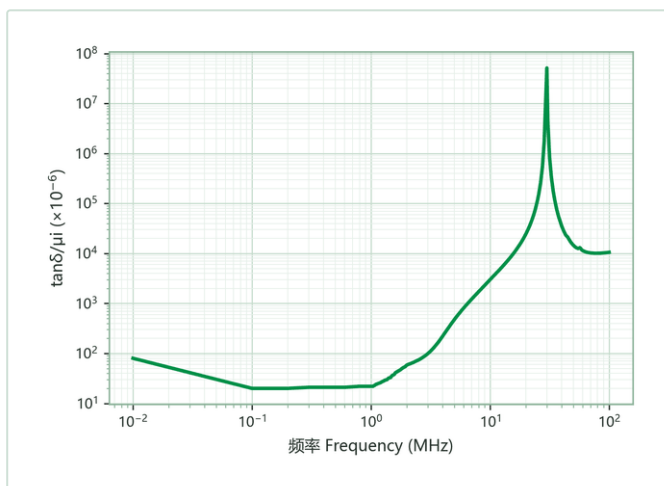
初始磁导率—温度特性
Initial Permeability vs. Temperature



复数磁导率—频率特性
Complex Permeability (μ' , μ'') vs. Frequency



静态磁化曲线
Static Magnetization Curves (B-H)



相对损耗因子—频率特性
Relative Loss Factor ($\tan\delta/\mu_i$) vs. Frequency